

INK0002AX SERIES

High speed switching
Silicon N-channel MOSFET

DESCRIPTION

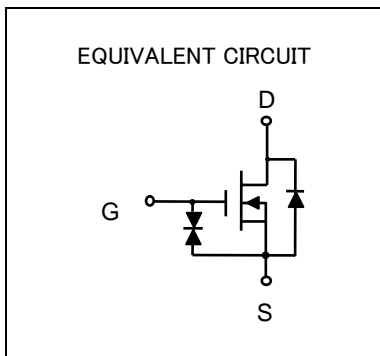
INK0002AX is a Silicon N-channel MOSFET.
This product is most suitable for low voltage use such as portable machinery, because of low voltage drive and low on resistance.

FEATURE

- Input impedance is high, and not necessary to consider a drive electric current.
- V_{th} is low, and drive by low voltage is possible. $V_{th}=0.6\sim 1.2V$
- Low on Resistance. $R_{on}=1.1\ \Omega$ (TYP)
- High speed switching.
- Small package for easy mounting.

APPLICATION

high speed switching, Analog switching



OUTLINE DRAWING

Unit: mm

INK0002AT2 (PRELIMINARY)	INK0002AM1
<p>JEITA, JEDEC: — ISAHAYA: T-USM</p> <p>TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>	<p>JEITA: SC-70 JEDEC: —</p> <p>TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>
<p>JEITA: SC-75A JEDEC: —</p> <p>TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>	<p>JEITA: SC-59 JEDEC: Similar to TO-236</p> <p>T TERMINAL CONNECTOR ①: GATE ②: SOURCE ③: DRAIN</p>

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High speed switching
Silicon N-channel MOSFET

MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING				UNIT
		INK0002AT2	INK0002AU1	INK0002AM1	INK0002AC1	
V _{DSS}	Drain-source voltage	30				V
V _{GSS}	Gate-source voltage	±8				V
I _D	Drain current	200				mA
P _D	Total power dissipation (Ta=25°C)	125(※)	150	200		mW
T _{ch}	Channel temperature	+125	+150			°C
T _{stg}	Range of Storage temperature	-55~+125	-55~+150			°C

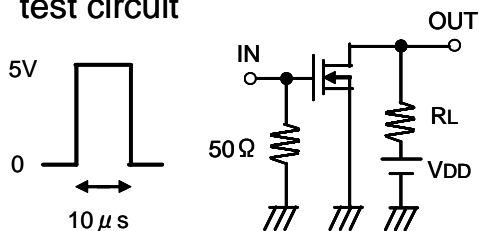
ELECTRICAL CHARACTERISTICS (Ta=25°C)

※package mounted on 9mm × 19mm × 1mm glass-epoxy substrate.

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
V _{(BR)DSS}	Drain-source breakdown voltage	I _D =100 μA, V _{GS} =0V	30	-	-	V
I _{GSS}	Gate-source leak current	V _{GS} =±5V, V _{DS} =0V	-	-	±0.5	μA
I _{DSS}	Zero gate voltage drain current	V _{DS} =30V, V _{GS} =0V	-	-	50	μA
V _{th}	Gate threshold voltage	I _D =250 μA, V _{DS} =V _{GS}	0.6	-	1.2	V
Y _{fs}	Forward transfer admittance	V _{DS} =10V, I _D =0.1A	-	300	-	mS
R _{DS(ON)}	Static drain-source on-state resistance	I _D =100mA, V _{GS} =4.0V	-	1.1	-	Ω
C _{iss}	Input capacitance	V _{DS} =10V, V _{GS} =0V, f=1MHz	-	33	-	pF
C _{oss}	Output capacitance	V _{DS} =10V, V _{GS} =0V, f=1MHz	-	6.8	-	pF
t _{ON}	Switching time	V _{DD} =5V, I _D =10mA V _{GS} =0~5V	-	12	-	ns
t _{OFF}			-	80	-	

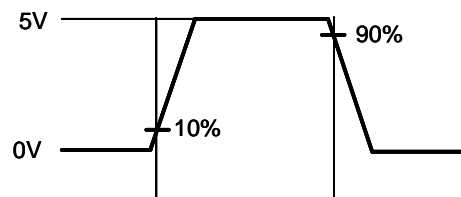
Switching time test condition

test circuit

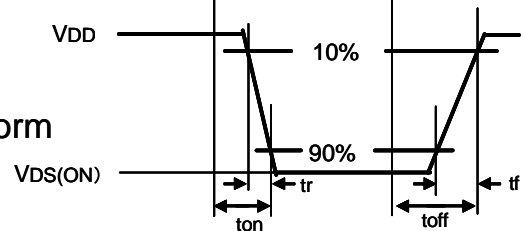


V_{DD}=5V
D.U. ≤ 1%
Common source
Ta=25°C

input waveform



output waveform





Marketing division, Marketing planning department

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Keep safety first in your circuit designs!

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TYPICAL CHARACTERISTICS

